

To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

Send any inquiries to <http://www.renesas.com/inquiry>.

EOL announced Product

The Renesas logo, consisting of a stylized 'R' followed by the word 'RENESAS' in a bold, sans-serif font.

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DATA SHEET

RENESAS

MOS FIELD EFFECT TRANSISTOR 2SJ356

P-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

The 2SJ356 is a P-channel MOS FET of a vertical type and is a switching element that can be directly driven by the output of an IC operating at 5 V.

This product has a low ON resistance and superb switching characteristics and is ideal for driving the actuators and DC/DC converters.

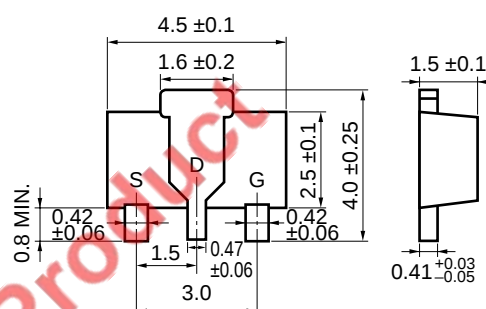
FEATURES

- Can be directly driven by 5-V IC
- Low ON resistance

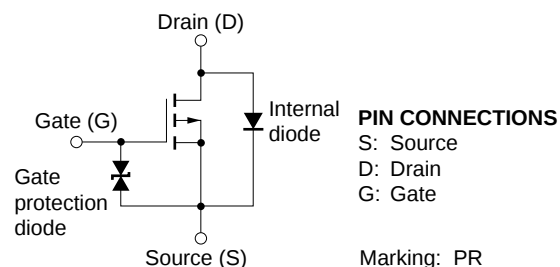
$R_{DS(on)} = 0.95 \Omega$ MAX. @ $V_{GS} = -4 \text{ V}$, $I_D = -1.0 \text{ A}$

$R_{DS(on)} = 0.50 \Omega$ MAX. @ $V_{GS} = -10 \text{ V}$, $I_D = -1.0 \text{ A}$

PACKAGE DIMENSIONS (in mm)



EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ \text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	V_{DS}	$V_{GS} = 0$	-60	V
Gate to Source Voltage	V_{GS}	$V_{DS} = 0$	-20/+10	V
Drain Current (DC)	$I_{D(DC)}$		±2.0	A
Drain Current (Pulse)	$I_{D(pulse)}$	PW ≤ 10 ms Duty cycle ≤ 1 %	±4.0	A
Total Power Dissipation	P_T	16 cm ² × 0.7 mm, ceramic substrate used	2.0	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

The internal diode connected between the gate and source of this product is to protect the product from static electricity. If the product is used in a circuit where the rated voltage of the product may be exceeded, connect a protection circuit.

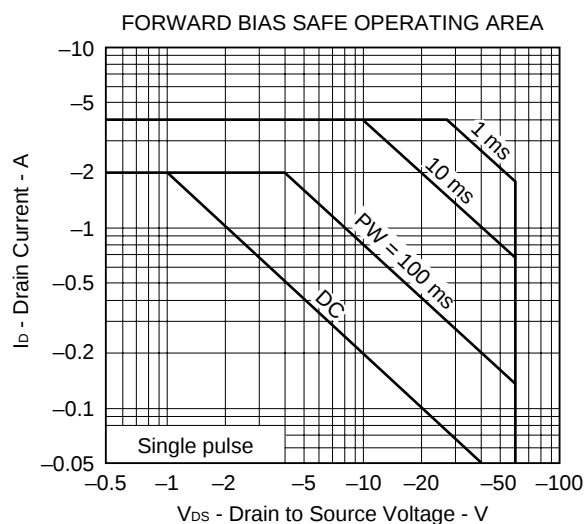
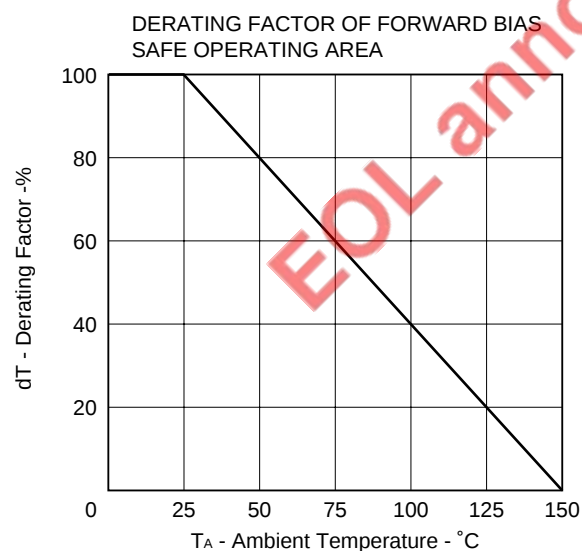
Take adequate preventive measures against static electricity when handling this product.

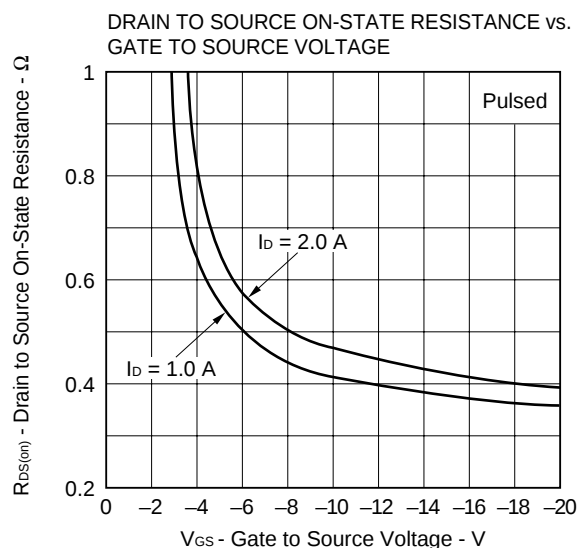
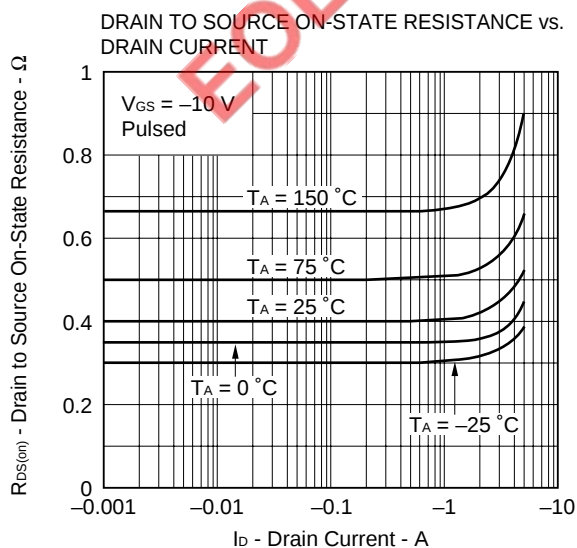
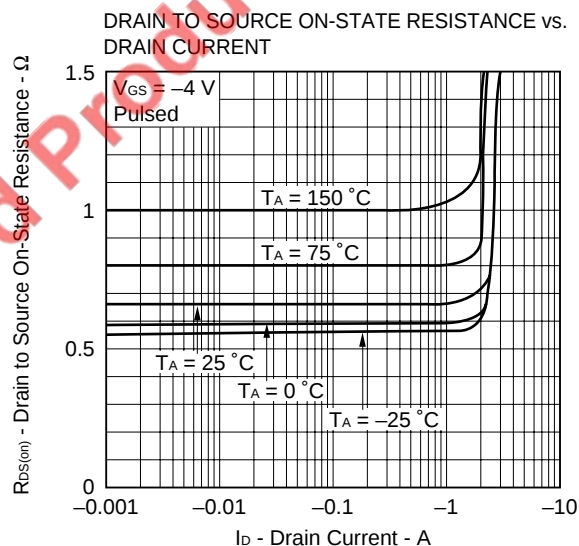
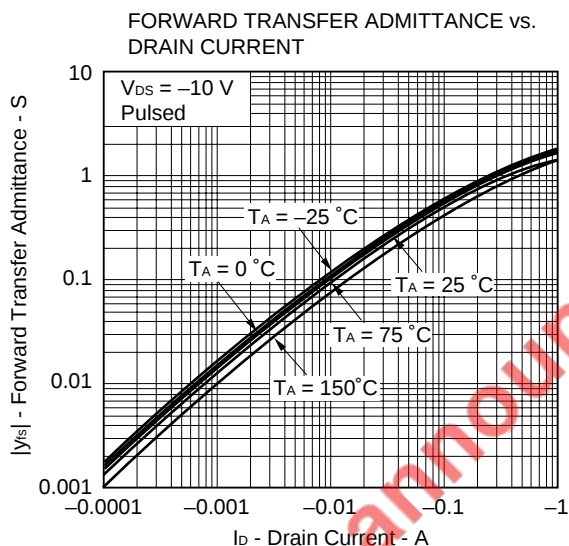
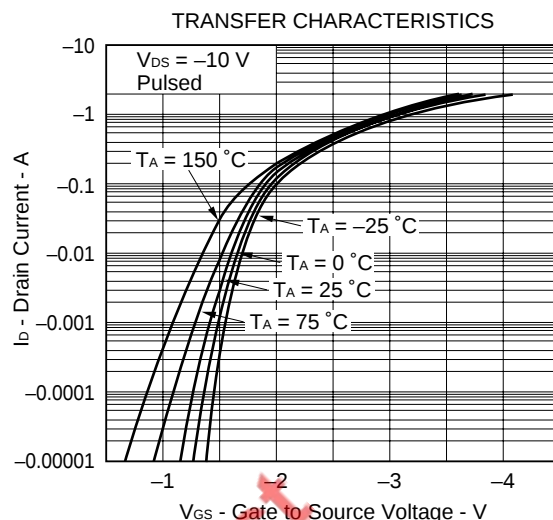
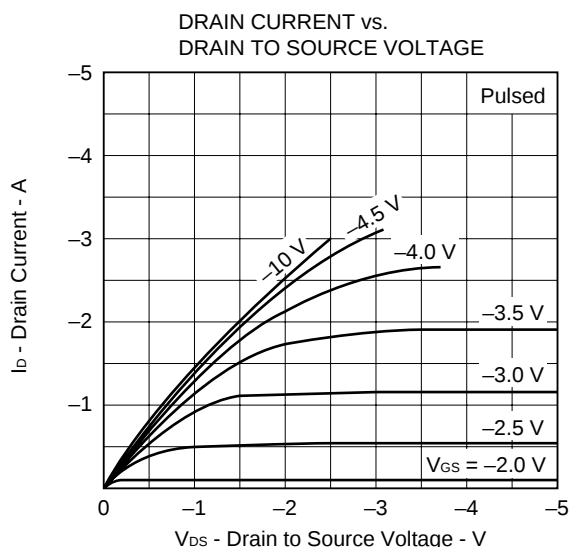
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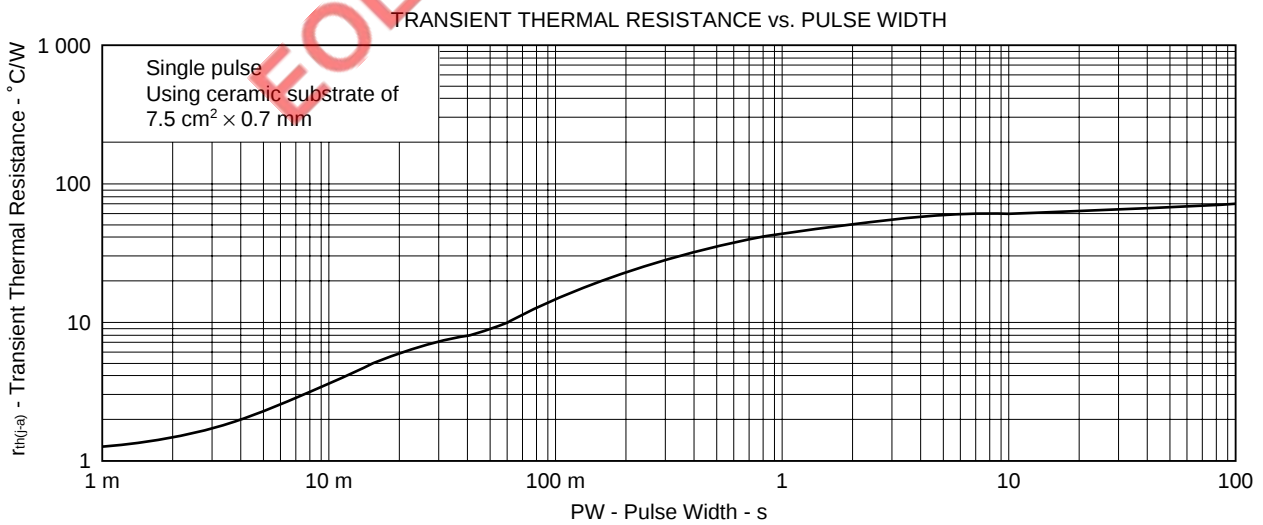
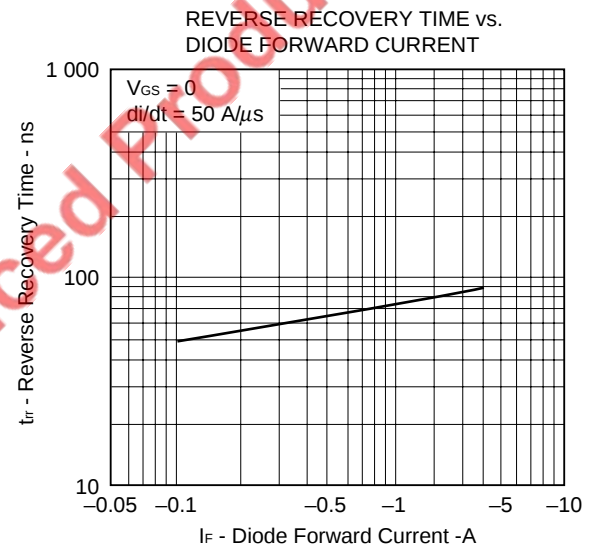
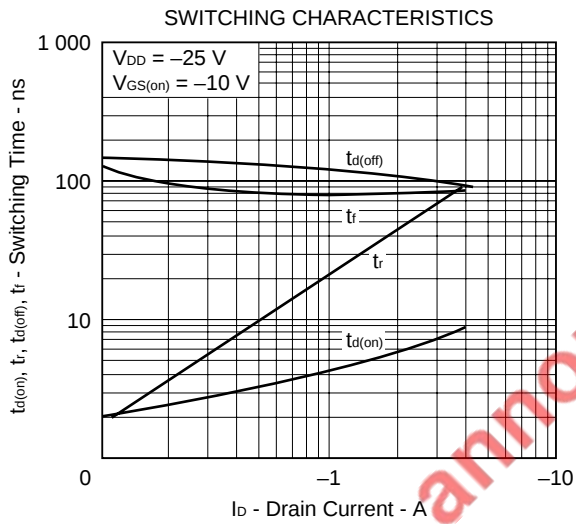
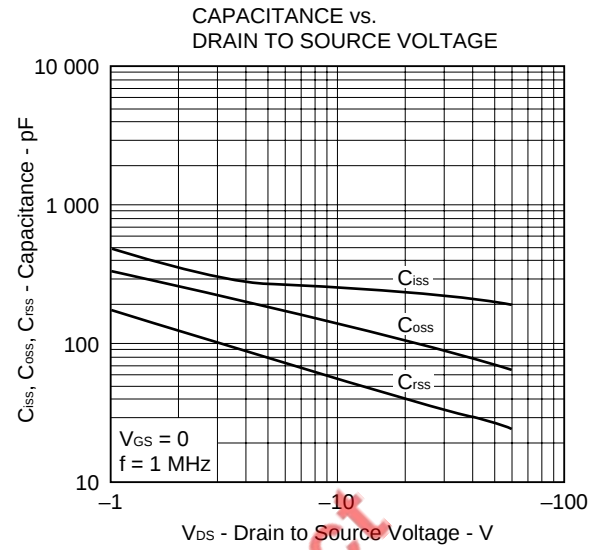
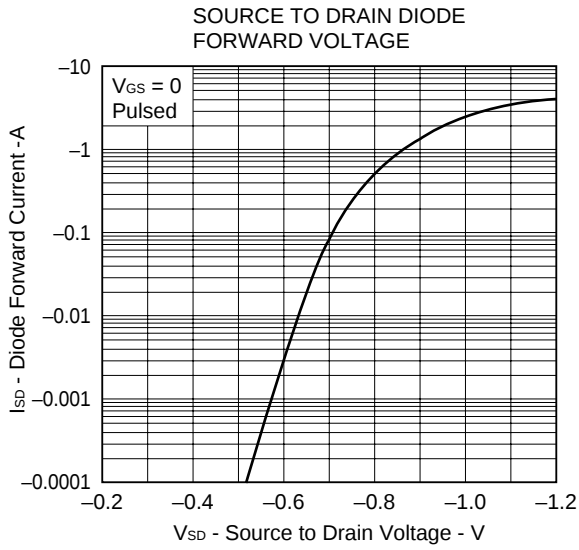
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	I_{DSS}	$V_{DS} = -60\text{ V}$, $V_{GS} = 0$			-10	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = -16/+10\text{ V}$, $V_{DS} = 0$			± 10	μA
Gate Cut-Off Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ mA}$	-1.0	-1.4	-2.0	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{ V}$, $I_D = -1.0\text{ A}$	1.0			S
Drain to Source On-State Resistance	$R_{DS(on)1}$	$V_{GS} = -4\text{ V}$, $I_D = -1.0\text{ A}$		0.65	0.95	Ω
Drain to Source On-State Resistance	$R_{DS(on)2}$	$V_{GS} = -10\text{ V}$, $I_D = -1.0\text{ A}$		0.41	0.50	Ω
Input Capacitance	C_{iss}	$V_{DS} = -10\text{ V}$, $V_{GS} = 0$, $f = 1.0\text{ MHz}$		270		pF
Output Capacitance	C_{oss}			145		pF
Reverse Transfer Capacitance	C_{rss}			55		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -25\text{ V}$, $I_D = -1.0\text{ A}$ $V_{GS(on)} = -10\text{ V}$ $R_G = 10\ \Omega$, $R_L = 25\ \Omega$		4.3		ns
Rise Time	t_r			21		ns
Turn-Off Delay Time	$t_{d(off)}$			115		ns
Fall Time	t_f			75		ns
Gate Input Charge	Q_G	$V_{DS} = -48\text{ V}$, $V_{GS} = -10\text{ V}$, $I_D = -2.0\text{ A}$, $I_G = -2\text{ mA}$		11.6		nC
Gate to Source Charge	Q_{GS}			1.0		nC
Gate to Drain Charge	Q_{GD}			3.8		nC
Internal Diode Reverse Recovery Time	t_{rr}	$I_F = 2.0\text{ A}$, $di/dt = 50\text{ A}/\mu\text{s}$		82		ns
Internal Diode Reverse Recovery Charge	Q_{rr}			94		nC

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)







REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

EOL announced Product

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.